Triacs sensitive gate

BT136B series E

GENERAL DESCRIPTION

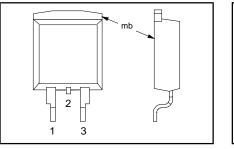
Passivated, sensitive gate triacs in a plastic envelope suitable for surface mounting, intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	UNIT
V _{drm} I _{t(rms)} I _{tsm}	BT136B- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	600E 600 4 25	800E 800 4 25	V A A

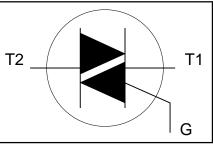
PINNING - SOT404

PIN	DESCRIPTION	
1	main terminal 1	
2	main terminal 2	
3	gate	
mb	main terminal 2	



PIN CONFIGURATION

SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V _{drm}	Repetitive peak off-state voltages		-	-600 600 ¹	-800 800	v
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 107$ °C full sine wave; $T_j = 25$ °C prior to surge	-	4		A
		t = 20 ms	-	2	5	A
l ² t	1 ² t for fusing	t = 16.7 ms t = 10 ms	-		7 .1	A A ² s
dl _T /dt	I ² t for fusing Repetitive rate of rise of on-state current after	$I_{TM} = 6 \text{ A}; I_G = 0.2 \text{ A};$ $dI_C/dt = 0.2 \text{ A}/\mu\text{s}$	-	3	. I	AS
	triggering	T2+ G+	-		0	A/μs
		T2+ G-	-		0	A/μs
		T2- G-	-		0	A/μs
1.	Peak gate current	T2- G+	-		0	A/μs Å
I _{GM} V _{GM}	Peak gate voltage				5	I V I
P _{GM}	Peak gate power		_		5	Ŵ
	Average gate power	over any 20 ms period	-		.5	W
T _{stg} T _j	Storage temperature Operating junction temperature		-40 -	15	50 25	Ĵ Ĵ

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 3 $A/\mu s$.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th i-a}	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle minimum footprint, FR4 board		- - 55	3.0 3.7 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$				
01		T2+	G+ -	2.5	10	mA
		T2+	G	4.0	10	mA
		T2- 0	G- -	5.0	10	mA
		T2- 0	G+ -	11	25	mA
I _L	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$				
-		T2+	G+ -	3.0	15	mA
		T2+	G- -	10	20	mA
		T2- 0		2.5	15	mA
		T2-0	G+ -	4.0	20	mA
I _H	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	2.2	15	mA
I _H V _T V _{GT}	On-state voltage	$I_T = 5 A$	-	1.4	1.70	V
V _{GT}	Gate trigger voltage	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	0.7	1.5	V
		$ V_{D} = 400 V; I_{T} = 0.1 A; T_{i} = 125 °C$	0.25	0.4	-	V
I _D	Off-state leakage current	$V_{D}^{b} = 400 \text{ V}; I_{T} = 0.1 \text{ A}; T_{j} = 125 ^{\circ}\text{C}$ $V_{D} = V_{DRM(max)}; T_{j} = 125 ^{\circ}\text{C}$	-	0.1	0.5	mA

DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of	V _{DM} = 67% V _{DRM(max)} ; T _j = 125 °C;	-	50	-	V/µs
t _{gt}	off-state voltage Gate controlled turn-on time	exponential waveform; gate open circuit $I_{TM} = 6 \text{ A}$; $V_D = V_{DRM(max)}$; $I_G = 0.1 \text{ A}$; $dI_G/dt = 5 \text{ A/}\mu s$	-	2	-	μs

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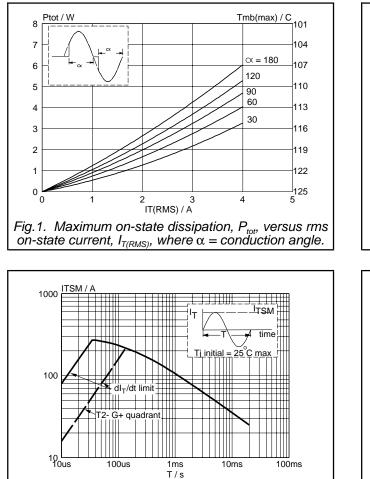
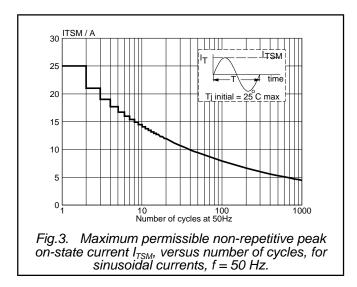
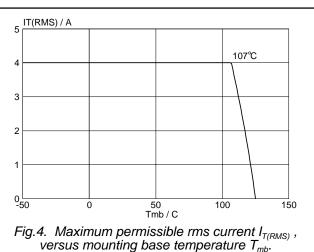


Fig.2. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \le 20ms$.





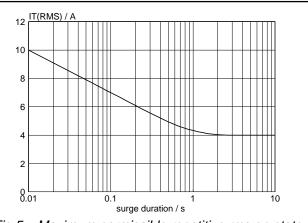
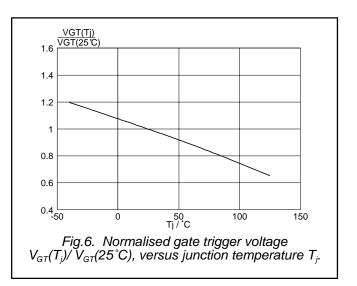
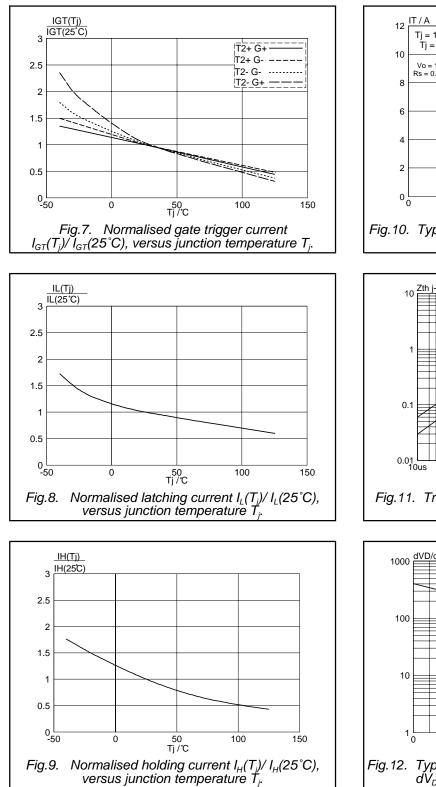


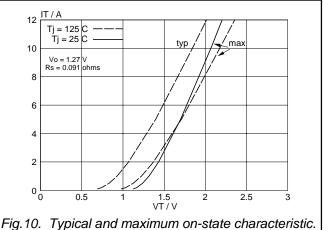
Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 107$ °C.

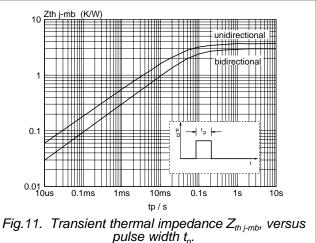


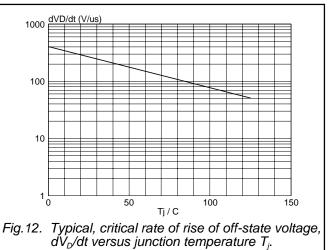
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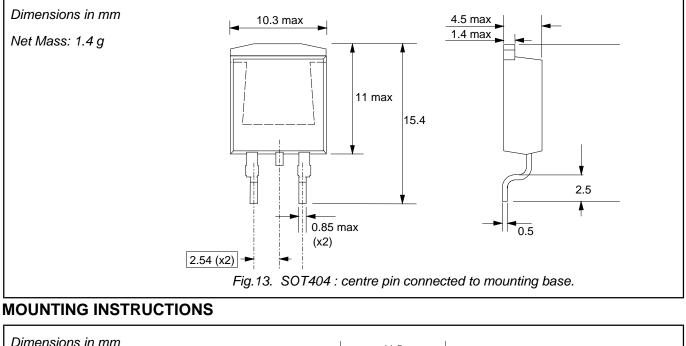


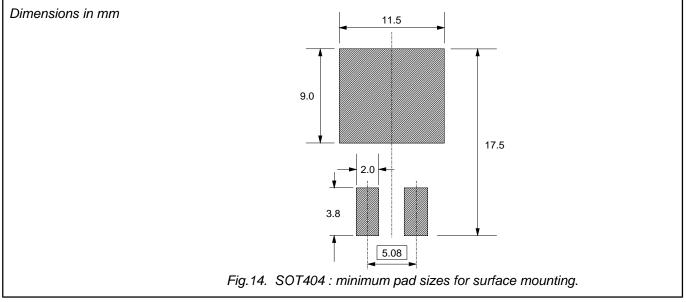
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Product specification

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MECHANICAL DATA





Notes

1. Plastic meets UL94 V0 at 1/8".

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DEFINITIONS

DATA SHEET STATUS				
DATA SHEET STATUS ²	PRODUCT STATUS ³	DEFINITIONS		
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice		
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in ordere to improve the design and supply the best possible product		
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A		
Limiting values				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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